

AZ1117C

General Description

The AZ1117C is a low dropout three-terminal regulator

The AZ1117C has been optimized for low voltage where transient response and minimum input voltage are critical. It provides current limit and thermal shutdown. Its circuit includes a trimmed bandgap reference to assure output voltage accuracy to be within $\pm 1\%$. On-chip thermal shutdown provides protection against a combination of high current and ambient temperature that would create excessive junction temperature.

The AZ1117C is available in 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, 5.0V fixed output voltage versions and ADJ output voltage version. The fixed versions integrate the adjust resistors. It is also available in an adjustable version which can set the output voltage with two external resistors.

The AZ1117C is available in the industry-standard TO-252-2 (1), TO-252-2 (2), TO-252-2 (3) and SOT-223 power packages.

Features

- Current Limit: 1.0A (Typ.)
- Output Noise from 10Hz to 10KHz: 0.003% of V_{OUT}
- PSRR at I_{OUT} =300mA and f=120Hz: 70dB
- Output Voltage Accuracy: ±1% (Except 1.2V version)
- · On-chip Thermal Shutdown
- Maximum Quiescent Current: I_{QMAX}=6mA
- Compatible with Low ESR Ceramic Capacitor
- Operation Junction Temperature: -20 to 125°C

Applications

- · USB Device
- · Add-on Card
- DVD Player
- PC Motherboard

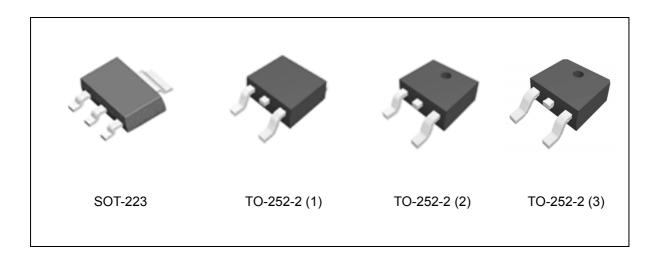


Figure 1. Package Types of AZ1117C



AZ1117C

Pin Configuration

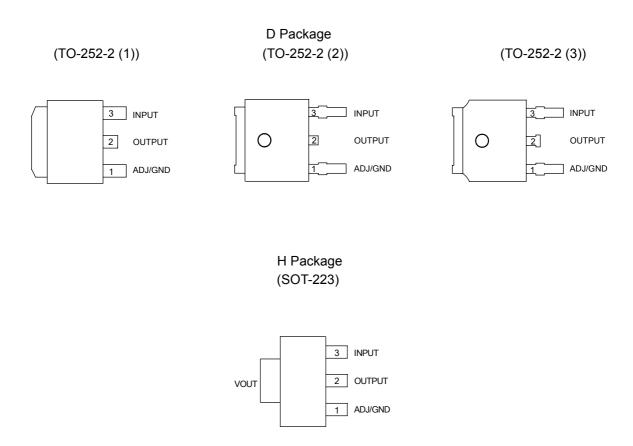


Figure 2. Pin Configuration of AZ1117C (Top View)

AZ1117C



LOW DROPOUT LINEAR REGULATOR

Functional Block Diagram

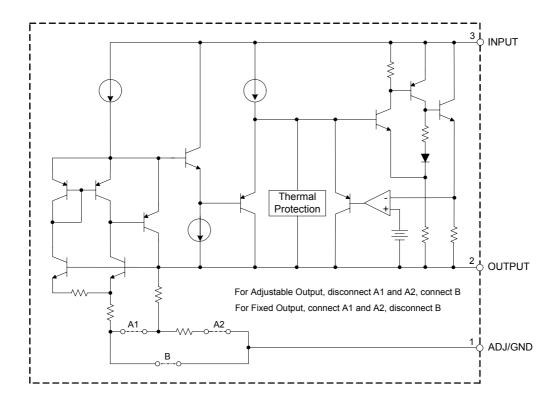
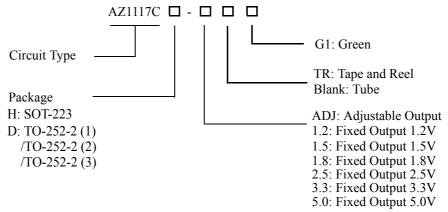


Figure 3. Functional Block Diagram of AZ1117C



AZ1117C

Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type
		AZ1117CH-ADJTRG1	GH15B	Tape & Reel
		AZ1117CH-1.2TRG1	GH16B	Tape & Reel
		AZ1117CH-1.5TRG1	GH15C	Tape & Reel
SOT-223		AZ1117CH-1.8TRG1	GH16C	Tape & Reel
		AZ1117CH-2.5TRG1	GH15D	Tape & Reel
		AZ1117CH-3.3TRG1	GH16D	Tape & Reel
		AZ1117CH-5.0TRG1	GH15E	Tape & Reel
		AZ1117CD-ADJG1	AZ1117CD-ADJG1	Tube
		AZ1117CD-ADJTRG1	AZ1117CD-ADJG1	Tape & Reel
		AZ1117CD-1.2G1	AZ1117CD-1.2G1	Tube
	-20 to 125°C	AZ1117CD-1.2TRG1	AZ1117CD-1.2G1	Tape & Ree
		AZ1117CD-1.5G1	.5G1 AZ1117CD-1.5G1	
		AZ1117CD-1.5TRG1	AZ1117CD-1.5G1	Tape & Reel
TO-252-2 (1)		AZ1117CD-1.8G1	AZ1117CD-1.8G1	Tube
/TO-252-2 (2) /TO-252-2 (3)		AZ1117CD-1.8TRG1	AZ1117CD-1.8G1	Tape & Reel
		AZ1117CD-2.5G1	AZ1117CD-2.5G1	Tube
		AZ1117CD-2.5TRG1 AZ1117CD-2.5G1 AZ1117CD-3.3G1 AZ1117CD-3.3G1 AZ1117CD-3.3TRG1 AZ1117CD-3.3G1 AZ1117CD-5.0G1 AZ1117CD-5.0G1		Tape & Reel
				Tube
				Tape & Reel
				Tube
		AZ1117CD-5.0TRG1	AZ1117CD-5.0G1	Tape & Reel

BCD Semiconductor's products, as designated with "G1" suffix in the part number, are RoHS compliant and Green.



AZ1117C

Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value		Unit		
Input Voltage	V _{IN}		18			
Operating Junction Temperature Range	T_{J}	150		150		°C
Storage Temperature Range	T _{STG}	-65 to 150		°C		
	θ_{JA}	SOT-223	150			
Thermal Resistance (No Heatsink)		TO-252-2 (1)/TO-252-2 (2)/ TO-252-2 (3)	128	°C/W		
Lead Temperature (Soldering, 10sec)	T_{LEAD}	260		°C		

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Input Voltage	V _{IN}		15	V
Operating Junction Temperature Range	T_{J}	-20	125	°C



AZ1117C

Electrical Characteristics AZ1117C-ADJ Electrical Characteristics

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Deference Voltage	V			1.238	1.250	1.262	**
Reference Voltage	V _{REF}	1.5V≤V _{IN} -V _{OUT} ≤10V		1.225	1.250	1.270	V
Line Regulation	V _{RLINE}	151/41 11 4011			0.001	0.1	%
Eme Regulation	' KLINE	$1.5V \le V_{\text{IN}} - V_{\text{OUT}} \le 10V$				0.2	/0
Load Regulation	V _{RLOAD}				0.4	1.0	%
Dropout Voltage	V _{DROP}	ΔV_{REF} =1%, I_{OUT} =0.8A	SOT-223		1.2	1.3	V
Current Limit	I _{LIMIT}			0.85	1		A
Adjust Pin Current					60	120	μΑ
Adjust Pin Current Change		$1.5V \le (V_{IN} - V_{OUT}) \le 10V$			0.2	5	μΑ
Minimum Load Current		$1.5V \le (V_{IN} - V_{OUT}) \le 10V$			1.7	5	mA
Ripple Rejection	PSRR	f=120Hz, C _{OUT} =22μF (V _{IN} -V _{OUT})=3V, I _{OUT} =300mA			70		dB
Temperature Stability					0.5		%
RMS Output Noise (% of V _{OUT})		T _A =25°C, 10Hz≤f≤10KHz			0.003		%
Thermal Shutdown		Junction Temperature			160		°C
Thermal Shutdown Hysteresis					16		°C
Thermal Resistance	$\theta_{ m JC}$	SOT-223			33		00/33
(Junction to Case)	OJC.	TO-252-2 (1)/TO-252-2 (2)/TO-2	252-2 (3)		22		°C/W



AZ1117C

Electrical Characteristics (Continued) AZ1117C-1.2 Electrical Characteristics

Parameter	Symbol	Condition	18	Min	Тур	Max	Unit
Output Voltage	V			1.176	1.2	1.224	**
Output voltage	V _{OUT}	3.2V≤V _{IN} ≤10V		1.152	1.2	1.228	V
Line Regulation	V _{RLINE}	157747 17 41077			0.5	6	mV
Line Regulation	' KLINE	$1.5V \le V_{IN} - V_{OUT} \le 10V$				10	111 V
Load Regulation	V _{RLOAD}				2	15	mV
Dropout Voltage	V _{DROP}	ΔV_{OUT} =1%, I_{OUT} =0.8A	SOT-223		1.2	1.3	V
Current Limit	I _{LIMIT}			0.85	1		A
Quiescent Current	I_Q	I _{OUT} =0			4	6	mA
Ripple Rejection	PSRR	f=120Hz, C _{OUT} =22μF (V _{IN} -V _{OUT})=3V, I _{OUT} =300)mA		70		dB
Temperature Stability					0.5		%
RMS Output Noise (% of V _{OUT})		T _A =25°C, 10Hz≤f≤10KHz			0.003		%
Thermal Shutdown		Junction Temperature			160		°C
Thermal Shutdown Hysteresis					16		°C
Thermal Resistance	$\theta_{ m JC}$	SOT-223			33		°C/W
(Junction to Case)	3,10	TO-252-2 (1)/TO-252-2 (2).	/TO-252-2 (3)		22		C/W



AZ1117C

Electrical Characteristics (Continued) AZ1117C-1.5 Electrical Characteristics

Parameter	Symbol	Conditions	3	Min	Тур	Max	Unit	
Output Valtage	V			1.485	1.5	1.515		
Output Voltage	V _{OUT}	3.5V≤V _{IN} ≤10V	$3.5V \le V_{IN} \le 10V$		1.5	1.530	V	
Line Regulation	V _{RLINE}	1.51/.01/			0.5	6	mV	
Line Regulation	' KLINE	1.5V≤V _{IN} -V _{OUT} ≤10V				10	111 V	
Load Regulation	V _{RLOAD}				2	15	mV	
Dropout Voltage	V _{DROP}	ΔV_{OUT} =1%, I_{OUT} =0.8A	SOT-223		1.2	1.3	V	
Current Limit	I _{LIMIT}		<u>.</u>	0.85	1		A	
Quiescent Current	I_Q	I _{OUT} =0	I _{OUT} =0		4	6	mA	
Ripple Rejection	PSRR	f=120Hz, C _{OUT} =22μF			70		dB	
		$(V_{IN}-V_{OUT})=3V$, $I_{OUT}=300n$	nA					
Temperature Stability					0.5		%	
RMS Output Noise		T _A =25°C, 10Hz≤f≤10KHz			0.003		%	
(% of V _{OUT})								
Thermal Shutdown		Junction Temperature			160		°C	
Thermal Shutdown					16		°C	
Hysteresis					10			
Thermal Resistance	$\theta_{ m JC}$	SOT-223			33		°C/W	
(Junction to Case)	- 10	TO-252-2 (1)/TO-252-2 (2)/TO-252-2 (3)			22		C/ W	



AZ1117C

Electrical Characteristics (Continued) AZ1117C-1.8 Electrical Characteristics

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Outrast Walters	V			1.782	1.8	1.818	
Output Voltage	V _{OUT}	3.8V≤V _{IN} ≤10V	$3.8V \le V_{IN} \le 10V$		1.8	1.836	V
Line Regulation	V _{RLINE}	151/4/ 1/ 101/			0.5	6	mV
Line Regulation	' KLINE	1.5V≤V _{IN} -V _{OUT} ≤10V				10	111 V
Load Regulation	V _{RLOAD}				2	15	mV
Dropout Voltage	V _{DROP}	ΔV_{OUT} =1%, I_{OUT} =0.8A	SOT-223		1.2	1.3	V
Current Limit	I _{LIMIT}			0.85	1		A
Quiescent Current	I_Q	I _{OUT} =0			4	6	mA
Ripple Rejection	PSRR	f=120Hz, C _{OUT} =22μF			70		dB
		$(V_{IN}-V_{OUT})=3V$, $I_{OUT}=300$ mA			, ,		42
Temperature Stability					0.5		%
RMS Output Noise		T _A =25°C, 10Hz≤f≤10KHz			0.003		%
(% of V _{OUT})							
Thermal Shutdown		Junction Temperature			160		°C
Thermal Shutdown					16		°C
Hysteresis					10		
Thermal Resistance	$\theta_{ m JC}$	SOT-223			33		°C/W
(Junction to Case)	3,10	TO-252-2 (1)/TO-252-2 (2)/TO-	-252-2 (3)		22		C/W



AZ1117C

Electrical Characteristics (Continued) AZ1117C-2.5 Electrical Characteristics

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Outrot Valta as	V			2.475	2.5	2.525	
Output Voltage	V _{OUT}	4.5V≤V _{IN} ≤10V		2.455	2.5	2.545	V
Line Regulation	V _{RLINE}	151/4/ 1/ 1/01/			0.5	6	mV
Line Regulation	' KLINE	$1.5V \le V_{IN} - V_{OUT} \le 10V$				10	III V
Load Regulation	V _{RLOAD}				2	15	mV
Dropout Voltage	V _{DROP}	ΔV_{OUT} =1%, I_{OUT} =0.8A	SOT-223		1.2	1.3	V
Current Limit	I _{LIMIT}			0.85	1		A
Quiescent Current	I_Q	I _{OUT} =0			4	6	mA
Ripple Rejection	PSRR	f=120Hz, C _{OUT} =22μF (V _{IN} -V _{OUT})=3V, I _{OUT} =300m	f=120Hz, C_{OUT} =22 μ F (V_{IN} - V_{OUT})=3 V , I_{OUT} =300mA		70		dB
Temperature Stability					0.5		%
RMS Output Noise (% of V _{OUT})		T _A =25°C, 10Hz≤f≤10KHz			0.003		%
Thermal Shutdown		Junction Temperature			160		°C
Thermal Shutdown Hysteresis					16		°C
Thermal Resistance	$\theta_{ m JC}$	SOT-223			33		°C/W
(Junction to Case)	10	TO-252-2 (1)/TO-252-2 (2)/TO-252-2 (3)			22		C/W



AZ1117C

Electrical Characteristics (Continued) AZ1117C-3.3 Electrical Characteristics

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Output Voltage	V			3.267	3.3	3.333	
Output voltage	V _{OUT}	5.3V≤V _{IN} ≤10V	$5.3V \le V_{IN} \le 10V$			3.365	V
Line Regulation	V _{RLINE}	151/3/ 1/ 401/			0.5	6	mV
Line Regulation	KLINE	$1.5V \le V_{IN} - V_{OUT} \le 10V$				10	III V
Load Regulation	V _{RLOAD}				2	15	mV
Dropout Voltage	V_{DROP}	ΔV_{OUT} =1%, I_{OUT} =0.8A	SOT-223		1.2	1.3	V
Current Limit	I _{LIMIT}			0.85	1		A
Quiescent Current	I_Q	I _{OUT} =0	I _{OUT} =0		4	6	mA
Ripple Rejection	PSRR	f=120Hz, C _{OUT} =22μF (V _{IN} -V _{OUT})=3V, I _{OUT} =300m	A		70		dB
Temperature Stability					0.5		%
RMS Output Noise (% of V _{OUT})		T _A =25°C, 10Hz≤f≤10KHz			0.003		%
Thermal Shutdown		Junction Temperature			160		°C
Thermal Shutdown Hysteresis					16		°C
Thermal Resistance	$\theta_{ m JC}$	SOT-223			33		°C/W
(Junction to Case)	o je	TO-252-2 (1)/TO-252-2 (2)/TO	D-252-2 (3)		22		C/W



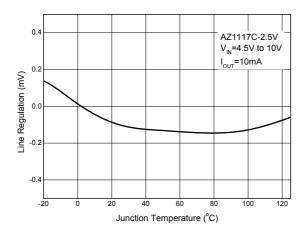
AZ1117C

Electrical Characteristics (Continued) AZ1117C-5.0 Electrical Characteristics

Parameter	Symbol	Condition	ıs	Min	Тур	Max	Unit
Output Voltage	V.			4.950	5.0	5.050	
Output Voltage	V _{OUT}	6.5V≤V _{IN} ≤10V		4.900	5.0	5.100	V
Line Regulation	V _{RLINE}	151/4/ 1/ (101/			0.5	6	mV
Line regulation	' KLINE	1.5V≤V _{IN} -V _{OUT} ≤10V				10	111 V
Load Regulation	V _{RLOAD}				2	15	mV
Dropout Voltage	V _{DROP}	ΔV_{OUT} =1%, I_{OUT} =0.8A	SOT-223		1.2	1.3	V
Current Limit	I _{LIMIT}			0.85	1		A
Quiescent Current	I_Q	I _{OUT} =0			4	6	mA
Ripple Rejection	PSRR	f=120Hz, C _{OUT} =22μF (V _{IN} -V _{OUT})=3V, I _{OUT} =300n	m A		70		dB
		(v IN- v OUT)=3 v, 1OUT=3001	IIIA				
Temperature Stability					0.5		%
RMS Output Noise (% of V _{OUT})		T _A =25°C, 10Hz≤f≤10KHz			0.003		%
Thermal Shutdown		Junction Temperature			160		°С
Thermal Shutdown Hysteresis					16		°C
Thermal Resistance	$\theta_{ m JC}$	SOT-223			33		0C/W
(Junction to Case)	o)C	TO-252-2 (1)/TO-252-2 (2)/T	ГО-252-2 (3)		22		°C/W



Typical Performance Characteristics



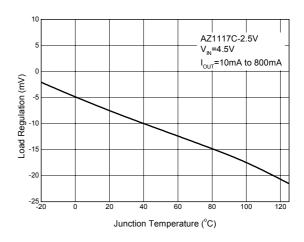
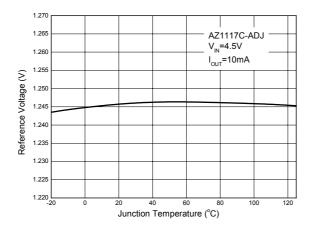


Figure 4. Line Regulation vs. Junction Temperature

Figure 5. Load Regulation vs. JunctionTemperature



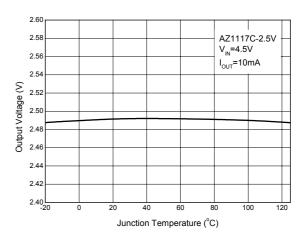


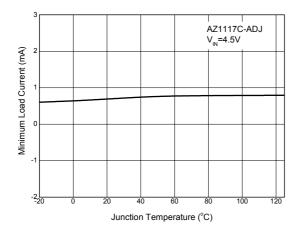
Figure 6. Reference Voltage vs. Junction Temperature

Figure 7. Output Voltage vs. Junction Temperature



AZ1117C

Typical Performance Characteristics (Continued)



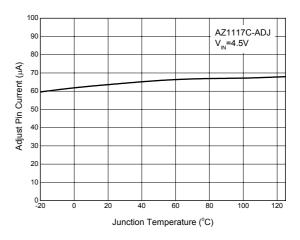
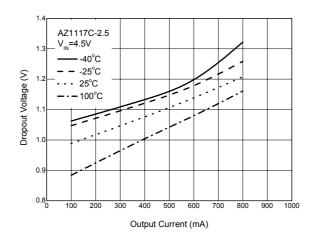


Figure 8. Minimum Load Current vs. Junction Temperature

Figure 9. Adjust Pin Current vs. Junction Temperature



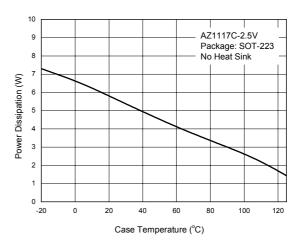


Figure 10. Dropout Voltage vs. Output Current

Figure 11. Power Dissipation vs. Case Temperature



Typical Performance Characteristics (Continued)

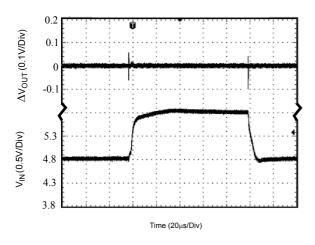


Figure 12. Line Transient Response

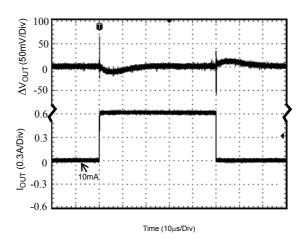


Figure 13. Load Transient Response

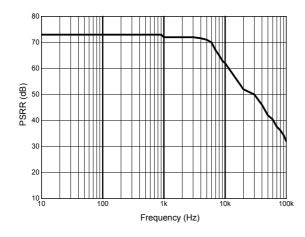


Figure 14. PSRR vs. Frequency

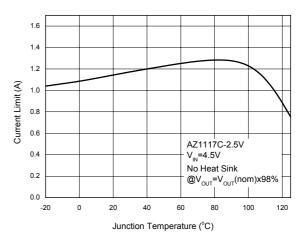


Figure 15. Current Limit vs. Junction Temperature



AZ1117C

Typical Performance Characteristics (Continued)

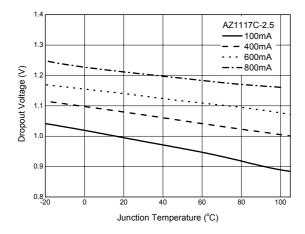
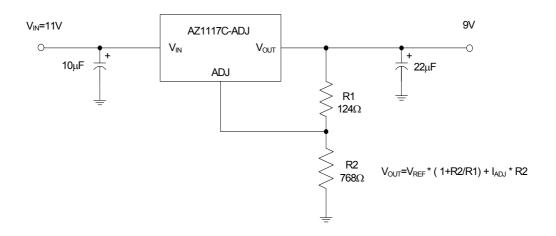


Figure 16. Dropout Voltage vs. Junction Temperature



AZ1117C

Typical Applications



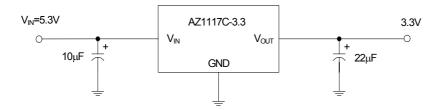


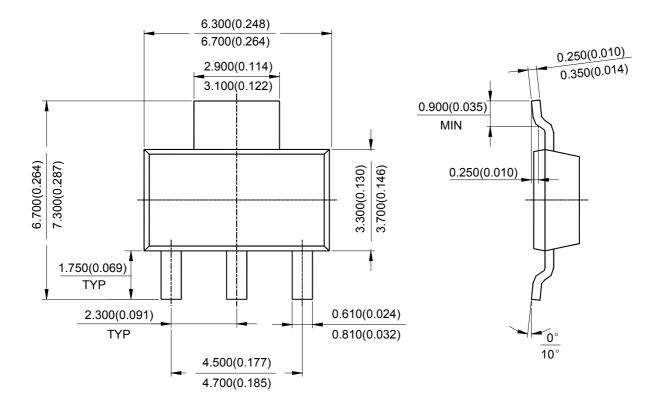
Figure 17. Typical Applications of AZ1117C

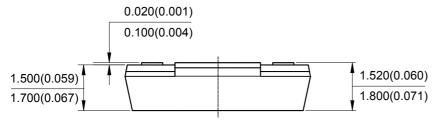


AZ1117C

Mechanical Dimensions

SOT-223 Unit: mm(inch)



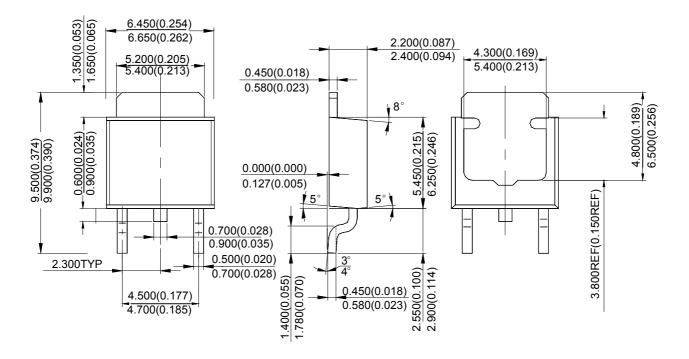




AZ1117C

Mechanical Dimensions (Continued)

TO-252-2 (1) Unit: mm(inch)



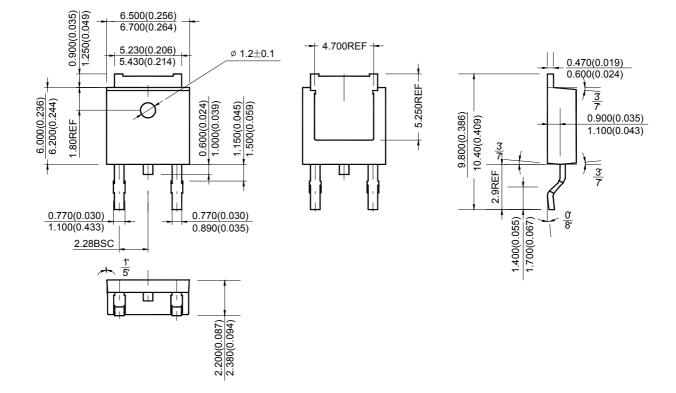


AZ1117C

Mechanical Dimensions (Continued)

TO-252-2 (2)





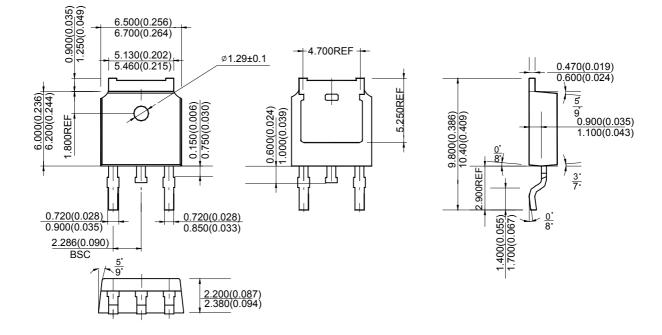


AZ1117C

Mechanical Dimensions (Continued)

TO-252-2 (3)

Unit: mm(inch)







BCD Semiconductor Manufacturing Limited

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